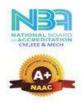


M.I.E.T. ENGINEERING COLLEGE

(Approved by AICTE, New Delhi, Affiliated to Anna University, Chennai)
UG - CSE, EEE & MECH Programs Accredited by NBA, New Delhi
Accredited with 'A+' grade by NAAC
An ISO 9001:2015 Certified Institution
Recognized by UGC under section 2(f) & 12(B) of UGC Act, 1956
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DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

Regulation-2021 UG

COURSE OUTCOME, CO-PO/PSO MAPPING, COURSE-PO/PSO MAPPING

	REGULATION – 2021		
ELECTRONICS AND COMMUNICATION ENGINEERING			
SEMESTER I			
Sl. No. COURSE OUTCOME BT LI			
	C101/ HS3152/ Professional English-I		
C101.1	Engage learners in meaningful language and activities to improve their LSRW skills	K1	
C101.2	Enhance learner's awareness of general rules of writing for specific audience.	K2	
C101.3	Help learners understand the purpose audience contexts of different types of writing	K2	
C101.4	Develop analytical thinking skills for problem solving in communication contexts	K2	
C101.5	Demonstrate an understanding of job application and interview for internship and placement	K2	
C101.6	Enable learners of Engineering and Technology to develop their basic communication skill in English	K2	
	C102/ MA3151/Matrices And Calculus		
C102.1	Use the matrix algebra methods for solving practical problems.	К3	
C102.2	Apply differential calculus tools in solving various application problems.	K2	
C102.3	Able to use differential calculus ideas on several variable functions.	K2	
C102.4	Understand different methods of integration in solving practical problems.	K2	
C102.5	Apply multiple integral concepts in solving areas, volumes and other practical problems.	K2	
C102.6	Apply matrix and calculus in solving engineering problems.	K2	
	C103/ PH3151/Engineering Physics		
C103.1	Understand the static and dynamic behavior of the objects.	K1	
C103.2	Understand the wave motion and the properties of electromagnetic waves	K1	
C103.3	Gain knowledge on laser and its working principle in fiber optic communication.	K2	
C103.4	Get adequate information on electron particles in metals.	K2	

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C103.5	Gain knowledge on the application of quantum theory.	K2
C103.6	Gain knowledge about waves and particles in nature under various conditions.	K2
	C104/ CY3151/Engineering Chemistry	
C104.1	Understand the process of various water treatment and its remedial measure	K2
C104.2	Know about the various methods of preparation of nano materials	K1
C104.3	Gain the knowledge of phase rule and composites for material selection	K2
C104.4	Recommend suitable fuels for industries	K1
C104.5	Recognize various form of energy resources and its applications	K2
C104.6	Gain the various applications of nanomaterials in various field	K2
	C105 / GE3151/ Problem Solving And Python Programming	
C105.1	Demonstrate algorithm, flowchart for various programs	K1
C105.2	Do simple programs using python programming basics	K2
C105.3	Illustrate programs by using arrays and string functions	K2
C105.4	Develop simple programs using functions and pointers	K2
C105.5	Design mini projects with structures.	К3
C105.6	Develop applications using python Programming Language	K3
	C106 / GE8161/ Problem Solving And Python Programming laboratory	
C106.1	Understand the problem to develop the algorithm and the solutions for a simple computational problems	К3
C106.2	Know the basic programming construction in Python	K2
C106.3	Apply the programs in Python using conditionals and loops for solving problems	K2
C106.4	Use the data structures to decompose the python program.	K2
C106.5	Initialize the Python packages for developing software applications	К3
C106.6	Solve the various computing techniques for Python-based solutions to real world problems	K2

C107 / BS3171/ Physics And Chemistry Laboratory		
C107.1	Analyze the physical principle involved in the functioning of various measuring instruments	K2
C107.2	Access, process and analyze the data using mathematical models in describing physical reality	К3
C107.3	Determine the physical parameters in mechanics and optics that will nurture the students in all branches of Engineering	K2
C107.4	Determine the DO content in water sample by Winkler's method	К3
C107.5	Determine the amount of ions through volumetric techniques.	К3
C107.6	Determine the strength of acid using pH meter.	K2
	SEMESTER – II	
	C108 / HS3252/ Professional English-II	
C108.1	Engage learners in meaningful language and activities to improve their LSRW skills	K1
C108.2	Enhance learners awareness of general rules of writing for specific audience.	K1
C108.3	Help learners understand the purpose audience contexts of different types of writing	K2
C108.4	Develop analytical thinking skills for problem solving in communication contexts	K2
C108.5	Demonstrate an understanding of job application and interview for internship and placement	K1
C108.6	Enable learners of Engineering and Technology to develop their basic communication skill in English	K2
	C109 / MA3251/ Statistics And Numerical Methods	
C109.1	Apply the concept of testing of hypothesis for small and large samples in real life problems.	К3
C109.2	Apply the basic concepts of classifications of design of experiments in the field of agriculture.	К3
C109.3	Appreciate the numerical techniques of interpolation in various intervals and apply the numerical techniques of differentiation and integration for engineering problems.	K2
C109.4	Understand the knowledge of various techniques and methods for solving first and second order ordinary differential equations.	K2

tations with initial and bound agineering applications. It ign experiments and various K2 It is properties of materials K2 It their applications in K2 If their uses in nanoelectronic K2 If their uses of materials and their K2 If their uses of materials and their K2		
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K2		
rumentation Engineering		
ical circuits K1		
and generators K2		
ral machines for various K2		
instruments used in electrical K2		
tructure and protection K2		
ystem and its controlling K2		
C112 /GE3251/Engineering Graphics		
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ngineering drawing. K2		
3		

C112.3	Solve practical problems involving projection of lines.	К3
C112.4	Sketch all the views of engineering objects in free hand.	K2
C112.5	Draw the development of simple solids.	К3
C112.6	Draw the orthographic, isometric and perspective projections of simple solids	К3
	C113/EC3251/Circuit Analysis	
C113.1	Gain knowledge in understanding of ohms law, Kirchhoff's current and voltage law for the analysis of electrical circuits	K3
C113.2	Understand the network theorem and network analysis for AC and DC circuits to solve real time problems	K3
C113.3	Gain knowledge of characteristics sinusoids to analyze steady state response of R, L, C functions.	K2
C113.4	Understand the transient and steady state response of the circuits and frequency response of parallel and series resonance	K2
C113.5	Know about the concept of coupling in circuits and network topologies	K2
C113.6	Understand the concept of electrical theorems and the functioning of electrical systems for engineering applications.	К3
C114/GE3271/Engineering Practices Laboratory		
C114.1	Gets exposure regarding Joining operations in engineering materials.	K1
C114.2	Carry out the basic machining operations in engineering materials.	K2
C114.3	Carry out basic home electrical works and appliances	K2
C114.4	Measure the electrical quantities	K2
C114.5	Understand basic electronic components.	K2
C114.6	Integrate the components and gates using soldering practices.	К3
C115 / EC3271/Circuit Analysis Laboratory		
C115.1	Apply Kirchhoff's laws to solve simple and complex circuits.	K2
C115.2	Apply network theorems to solve simple and complex circuits.	K2
C113,2	Apply network theorems to solve simple and complex circuits.	K2

C115.3	Demonstrate the working of Analog & Digital oscilloscopes.	K2
C115.4	Determine the frequency response of RC & RLC transient circuits.	K2
C115.5	Use MATLAB to simulate series, parallel resonant RLC circuits.	К3
C115.6	To simulate three phase balanced and unbalanced star, delta network circuit using MATLAB.	К3
	SEMESTER III	
	C201/MA3355/ Random Processes and Linear Algebra	
C201.1	Explain the fundamental concepts of advanced algebra and their role in modern mathematics and applied contexts.	К3
C201.2	Demonstrate accurate and efficient use of advanced algebraic techniques.	К3
C201.3	Apply the concept of random processes in engineering disciplines.	K2
C201.4	Understand the fundamental concepts of probability with a thorough knowledge of standard distributions that can describe certain real-life phenomenon	К3
C201.5	Understand the basic concepts of one dimensional random variables and apply them to model engineering problems.	K2
C201.6	Understand the basic concepts of two dimensional random variables and apply them to model engineering problems.	K2
	C202/ CS3353/C Programming and Data Structures	
C202.1	Develop C programs for any real world/technical application.	К3
C202.2	Apply advanced features of C in solving problems.	К3
C202.3	Write functions to implement linear and non–linear data structure operations.	К3
C202.4	Suggest and use appropriate linear/non–linear data structure operations for solving a given problem.	K2
C202.5	Appropriately use sort and search algorithms for a given application.	К3
C202.6	Apply appropriate hash functions that result in a collision free scenario for data storage and retrieval	К3
	C203/EC3354/ Signals and Systems	
C203.1	To determine if a given system is linear/causal/stable	K2
C203.2	To determine the frequency components present in a deterministic signal	K2
C203.3	The characterize continuous LTI systems in the time domain and frequency	K3

C203.4	To characterize discrete LTI systems in the time domain and frequency	K3
C203.4	To compute the output of an LTI system in the time and frequency domains.	K2
C203.6	Describe the mathematical modelling of DT systems.	K2
	C204/ EC3353/ Electronic Devices and Circuits	
C204.1	Explain the structure and working operation of basic electronic devices	K2
C204.2	Design and analyze amplifiers.	K2
C204.3	Analyze frequency response of BJT and MOSFET amplifiers	K3
C204.4	Design and analyze feedback amplifiers and oscillator principles	K3
C204.5	Design and analyze power amplifiers and supply circuits.	K3
C204.6	To design the Power amplifier using MOSFET	K2
	C205 /EC3351/ Control Systems	
C205.1	Compute the transfer function of different physical systems	K1
C205.2	Analyze the time domain specification and calculate the steady state error.	K2
C205.3	Illustrate the frequency response characteristics of open loop and closed loop system response.	К3
C205.4	Analyze the stability using Routh and root locus techniques	К3
C205.5	Illustrate the state space model of a physical system and discuss the concepts of sampled data control system.	K2
C205.6	To design the digital control design using state feedback.	К3
	C206 / EC3352/ Digital Systems Design	
C206.1	Use Boolean algebra and simplification procedures relevant to digital logic	K2
C206.2	Design various combinational digital circuits using logic gates	К3
C206.3	Analyze and design synchronous sequential circuits	К3
C206.4	Analyze and design asynchronous sequential circuits.	К3
C206.5	Build logic gates and use programmable devices.	К3
C206.6	To Implement the combinational logic/sequential logic design using	K3
	standard ICs	KS
	C207 /EC3361/ Electronic devices and circuits Laboratory	
C207.1	Testing the Characteristics of PN Junction Diode and Zener diode	K3
C207.2	Testing the Characteristics of BJT device	К3
C207.3	Testing the Characteristics of MOSFET device	К3
C207.4	Design and Testing of BJT amplifiers	К3

C207.5	Design and Testing of MOSFET amplifiers	К3
C207.6	Testing the Operation of power amplifiers.	К3
C208 /CS3362/ C Programming and Data Structures Laboratory		
C208.1	Use different constructs of C and develop applications	K2
C208.2	Write functions to implement linear and non-linear data structure operations	K2
C208.3	Suggest and use the appropriate linear / non-linear data structure operations for a given problem	K3
C208.4	Apply appropriate hash functions that result in a collision free scenario for data storage and Retrieval	K3
C208.5	Implement Sorting and searching algorithms for a given application	K3
C208.6	Develop applications in C and Solve problems using various linear data structures algorithms.	К3
	SEMESTER IV	
	C209/EC3452/ Electromagnetic Fields	
C209.1	Relate the fundamentals of vector, coordinate system to electromagnetic concepts	К3
C209.2	Analyze the characteristics of Electrostatic field	K2
C209.3	Interpret the concepts of Electric field in material space and solve the boundary conditions	К3
C209.4	Explain the concepts and characteristics of Magneto Static field in material space and solve boundary conditions	K2
C209.5	Determine the significance of time varying fields	K3
C209.6	Discuss the principles of propagation of uniform plane waves	K2
	C210 /EC3401/Networks and Security	
C210.1	Demonstrate the Network Models, Layers and Functions.	K1
C210.2	Categorize and classify the Routing Protocols.	K2
C210.3	List the functions of the Transport and Application Layer.	K1
C210.4	Enumerate the network Security Mechanisms.	K2
C210.5	Discuss the Hardware Security Attacks and Countermeasures	К3
C210.6	Measure the performance and troubleshoot cyber security systems	K2
	C211/EC3451/Linear Integrated Circuits	
C211.1	Design linear and nonlinear applications of OP – AMPS	K2
C211.2	Design applications using analog multiplier and PLL	К3

C211.2	Design ADC and DAC using OD AMDS	170
C211.3	Design ADC and DAC using OP – AMPS	K3
C211.4	Generate waveforms using OP – AMP Circuits	К3
C211.5	Analyze special function ICs	K2
C211.6	Generate waveforms using operational amplifiers Circuits	К3
	C212/EC3492/Digital Signal Processing	
C212.1	Apply DFT for the analysis of digital signals and systems	К3
C212.2	Design IIR and FIR Filters	K3
C212.3	Characterize the effects of finite precision representation on digital filters	K2
C212.4	Design multirate filters	К3
C212.5	Apply adaptive filters appropriately in communication systems	К3
C212.6	Know the importance of various techniques used in signal processing such	
	as preprocessing, equalization and filtering.	K2
	C213/ EC3491/Communication Systems	
C213.1	Gain knowledge in amplitude modulation techniques.	K1
C213.2	Understand the concepts of Random Process to the design of communication systems.	K2
C213.3	Gain knowledge in digital techniques.	K1
C213.4	Gain knowledge in sampling	K1
C213.5	Gain knowledge in quantization.	K1
C213.6	Understand the importance of demodulation techniques	K2
	C214/GE3451/ENVIRONMENTAL SCIENCES AND SUSTAINABILITY	
C214.1	To recognize and understand the functions of environment, ecosystems and biodiversity and their conservation.	K2
C214.2	To identify the causes, effects of environmental pollution and natural disasters and contribute to the preventive measures in the society.	K2
C214.3	To identify and apply the understanding of renewable and non-renewable resources and contribute to the sustainable measures to preserve them for future generations.	K2
C214.4	To recognize the different goals of sustainable development and apply them for suitable technological advancement and societal development.	K3
C214.5	To demonstrate the knowledge of sustainability practices and identify green materials, energy cycles and the role of sustainable urbanization.	K2
C214.6	Perform case study on carbon prints	K3
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C215 / EC3461/ Communication Systems Laboratory		
C215.1	Design AM &FM Modulators for specific applications	K2
C215.2	Design Digital Modulators for specific applications	K2
C215.3	Compute the sampling frequency for digital modulation	K4
C215.4	Simulate & validate the various functional modules of communication system	K2
C215.5	Demonstrate knowledge in base band signaling schemes through implementation of digital modulation schemes.	K2
C215.6	Apply various channel coding schemes and demonstrate their capabilities towards the improvement of the noise performance of communication system	K3
	C216 /EC3462/Linear Integrated Circuits Laboratory	
C216.1	Analyze various types of feedback amplifiers	K2
C216.2	Design oscillators, tuned amplifiers, wave-shaping circuits and multivibrators	К3
C216.3	Model real-time applications using embedded-system concepts	K3
C216.4	Design and simulate feedback amplifiers, oscillators, tuned amplifiers, wave shaping circuits and multivibrators, filters using SPICE Tool.	K2
C216.5	Design amplifiers, oscillators, D-A converters using operational amplifiers.	K2
C216.6	Design filters using op-amp and perform an experiment on frequency response	K2
	SEMESTER V	
	C301 /EC3501/Wireless Communication	
C301.1	Understand the fundamental cellular concept and design of Cellular system	K2
C301.2	Understand Mobile Radio Propagation Mechanism	K2
C301.3	Understand the Concept of Fading	K2
C301.4	Understand the concept of Multiple Access Techniques	K2
C301.5	Describe a wireless channel and evolve system design specifications	K2
C301.6	Understand wireless Networks and design a cellular system based on resource available resources and traffic demands.	K2
C302/ EC3552/VLSI and Chip Design		
C302.1	Acquire in-depth knowledge of MOS and CMOS technologies	K2
C302.2	Perform analysis and design of combinational circuits	К3

C302.3	Perform analysis and design of sequential circuits and their clocking	К3
	strategies	
C302.4	Acquire in-depth knowledge about interconnects, memory architecture	K2
C302.5	Acquire knowledge about ASIC design	K2
C302.6	Design of FPGAs	К3
	C303/EC3551/Transmission Lines and RF Systems	
C303.1	Describe the losses and characteristics of transmission lines	K1
C303.2	Calculate the standing wave ratio and input impedance in high frequency transmission lines	K2
C303.3	Illustrate impedance matching by stubs using smith charts	К3
C303.4	Generalize the properties of TE and TM waves	K2
C303.5	Design a RF transceiver system for wireless communication	K3
C303.6	Compute high frequency line, power and impedance measurements	K2
C304/CEC345/Optical Communication and Network		
C304.1	Realize Basic Elements In Optical Fibers, Different Modes And Configurations.	K2
C304.2	Analyze The Transmission Characteristics Associated With Dispersion and Polarization Techniques.	К3
C304.3	Design Optical Sources And Detectors With Their Use In Optical Communication System.	К3
C304.4	Construct Fiber Optic Receiver Systems, Measurements And Techniques.	К3
C304.5	Design Optical Communication Systems And Its Networks.	K2
C304.6	Understand the Communication concepts and Network Techniques	K2
	C305 / CEC366/Image Processing	
C305.1	Understand the basic concept of Digital Image.	K2
C305.2	Operate on images using the techniques of smoothing, sharpening and enhancement.	К3
C305.3	Understand the restoration concepts and filtering techniques.	K2
C305.4	Learn the basics of segmentation, features extraction, compression and recognition methods for color models.	K2
C305.5	Use various coding techniques for image compression.	К3
C305.6	Analyze various image descriptors and features of image representation techniques.	К3

C306 /CEC352/Satellite Communication			
C306.1	Understand the basics of satellite orbits	K2	
C306.2	Understand the satellite segment and earth segment	K2	
C306.3	Analyze the various methods of satellite access	К3	
C306.4	Understand the applications of satellites	K2	
C306.5	Understand the basics of satellite Networks	K2	
C306.6	Analyze the various applications	K3	
C307/ MX3084/Disaster Risk reduction and management			
C307.1	Understand the concept of Hazards, Vulnerability and Disaster Risks.	K2	
C307.2	To enhance understanding on Hazards, Vulnerability and Disaster Risk Assessment prevention and risk reduction.	К3	
C307.3	Develop disaster response skills by adopting relevant tools and technology.	K2	
C307.4	Enhance awareness of institutional processes for Disaster response in the country.	K2	
C307.5	Develop rudimentary ability to respond to their surroundings with potential.	К3	
C307.6	Analyze the case studies in disaster and understand the disaster management concept.	К3	
	C308 / EC3561/VLSI Laboratory		
C308.1	Write HDL Code for basic digital circuits	К3	
C308.2	Write HDL Code for advanced digital circuits	К3	
C308.3	Implement digital circuits in FPGA board	К3	
C308.4	Synthesize, place, route IPs	К3	
C308.5	Design, simulate and extract layout of digital circuits	К3	
C308.6	Design and simulate analog circuits	К3	

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	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
C101.1	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C101.2	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C101.3	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C101.4	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C101.5	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C101.6	3	3	-	-	2	3	2	2	2	3	-	2	-	2
		•	•	(C102/M	A3151/	Matri	ces And	l Calcu	lus	•	•	•	
C102.1	3	3	2	3	-	-	-	-	-	-	-	2	-	2
C102.2	3	3	2	3	2		-	-	-	-	-	2	-	2
C102.3	3	3	3	2	2		-	-	-	-	-	2	-	2
C102.4	3	3	2	2	2		-	-	-	-	-	2	-	-
C102.5	3	3	3	2	2		-	-	-	-	-	2	-	2
C102.6	3	3	-	-	ı		-	-	-	-	_	-	-	2
		•	•		C103/	PH3151	/ Engi	neering	Physic	es	•	1	1	
C103.1	3	3	-	-	-	3	-	-	-	-	-	2	-	-
C103.2	3	3	-	-	-	2	-	-	-	-	-	2	-	-
C103.3	3	-	2	-	2	3	2	-	-	-	-	2	3	3
C103.4	3	3	-	2	1	-	-	-	-	-	-	2	-	-
C103.5	3	3	-	2	1	-	-	-	-	-	-	2	-	-
C103.6	3	3	2		1	-	-	-	-	-	-	2	-	-

				(C104/CY	8151-/	Engine	eering C	hemis	stry				
C104.1	3	3	2	2	2	2	2	-	_	-	-	2	-	2
C104.2	3	3	2	2	2	-	2	-	2	-	_	2	-	2
C104.3	3	2	2	2	-	-	-	-	-	-	-	2	-	2
C104.4	3	3	2	2	2	-	-	-	-	-	-	2	-	2
C104.5	3	3	2	2	2	2	-	-	-	-	-	2	-	2
C104.6	3	3	2	2	2	2	-	-	-	-	-	2	-	2
			C10	5/GE3	151/Prob	lem So	olving	And Pyt	hon I	Programi	ming			
C105.1	3	2	-	-	-	-	-	-	-	-	-	-	-	-
C105.2	3	2	2	-	-	-	-	-	-	-	_	-	-	-
C105.3	3	2	2	-	-	-	-	-	-	-	-	-	-	-
C105.4	3	2	2	2	2	-	-	-	-	-	_	-	-	-
C105.5	3	2	2	2	2	2	-	2		-	-	-	-	-
C105.6	3	2	2	2	2	2	-	2	-	-	-	-	-	-
		C1	06/GE	3171/P	roblem S	olving	And I	Python P	rogra	amming 1	Laborat	ory		
C106.1	3		-	-	-	-	-	-	-	-	-	-	-	-
C106.2	3	3	3	2	-	-	-	-	-	-	-	-	-	-
C106.3	3	3	3	2	-	-	-	-	-	-	_	-	-	-
C106.4	3	2	3	2	-	-	-	-	-	-	-	-	-	-
C106.5	3	2	3	2	-	-	-	-	-	-	-	-	-	-
C106.6	3	2	3	2	-	-	-	-	-	-	-	-	-	-
		<u> </u>		C107/	BS3171/I	Physics	And	Chemist	ry La	boratory	,	ı	ı	<u> </u>
C107.1	3	2	-	-	-	-	-	-	-	-	-	2	2	-
C107.2	3	2	-	-	-	-	-	-	-	-	-	2	-	-

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C107.3	3	3	-	-	•	-	-	-	-	-	-	2	-	-
C107.4	2	-	-	2	-	-	2	2	3	-	-	2	-	-
C107.5	2	-	-	3	-	-	2	2	2	-	-	2	-	-
C107.6	2	-	-	2	-	-	2	2	2	-	-	2	-	-
				,	C108/HS	3252/I	Profess	sional Er	nglish	-II				
C108.1	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C108.2	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C108.3	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C108.4	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C108.5	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C108.6	3	3	-	-	2	3	2	2	2	3	-	2	-	2
				C109/	MA3251	/Statist	tics An	d Nume	rical	Methods				
C109.1	3	3	2	-	2	2	-	-	-	-	-	2	-	2
C109.2	3	3	2	-	2	2	-	-	-	-	-	2	-	2
C109.3	3	3	2	2	2	2	_	-	-	-	-	2	-	2
C109.4	3	-	2	1	2	-	-	-	-	-	-	2	-	-
C109.5	3	2	2	2	2	2	-	-	-	-	-		-	-
C109.6	3	3	-	-	-	-	-	-	_	-	-	3	-	2
				C110/F	PH3254/I	Physics	For E	lectroni	cs En	gineering	3			
C110.1	3	2	-	-	2	-	2	-	-	-	-	2	2	-
C110.2	3	3	-	-	2	-	2	-	-	-	-	2	2	-
C110.3	3	2	-	2	2	-	2	-	-	-	-	2	2	-
C110.4	3	2	-	-	2	-	-	-	-	-	1	2	2	-
C110.5	3	2	-	2	2	-	2	-	-	-	-	2	2	-
C110.6	3	2	-	2	2	-	2	-	-	-	-	2	2	-

		C	111/B	E3254/	Electrica	l And	Instru	mentatio	on En	gineering	3			
C111.1	3	3	2	-	2	-	-	-	-	-	2	2	-	-
C111.2	3	3	2	-	2	-	-	-	-	-	2	2	-	-
C111.3	3	3	2	2	2	2	-	-	-	-	2	2	-	-
C111.4	3	3	2	-	2	2	-	-	-	-	2	2	-	-
C111.5	2	2	2	-	2	2	2	-	2	-	2	2	2	-
C111.6	2	2	2	2	2	2	2	-	2	-	2	2	2	-
		I		I	C112/G1	E3251/	Engin	eering G	raphi	cs				
C112.1	3	3	3	2	2	-	-	-	-	2	2	2	3	3
C112.2	3	3	3	2	2	-	-	-	-	2	2	2	3	3
C112.3	3	3	3	2	2	-	-	-	-	2	2	2	3	3
C112.4	3	3	3	2	2	-	-	-	-	2	2	2	3	3
C112.5	3	3	3	2	2	-	-	-	-	2	2	2	3	3
C112.6	-	-	-	-	-	-	_	-	-	-	-	-	-	-
		l		l	C113	3/EC32	25/Ciro	cuit Ana	lysis			I	•	
C113.1	3	2	2	-	2	-	-	-	-	-	-	2	-	2
C113.2	3	2	2	-	2	-	-	-	-	-	-	2	-	2
C113.3	3	2	2	-	2	-	_	-	-	-	-	2	-	2
C113.4	3	2	2	-	2	-	-	-	-	-	-	2	-	2
C113.5	3	2	2	-	2	-	-	-	-	-	-	2	-	2
C113.6	3	2	2	-	2	-	_	-	-	-	1	2	-	2
				C114	/GE3271	/Engin	eering	Practic	e Lab	oratory				
C114.1	3	-	-	-	-	-	_	-	-	-	-	-	2	2
C114.2	3	3	3	-	-	-	-	2	-	-	-	-	2	2

C114.3	3	3	3	-	_	-	-	2	-	-	-		-	2	2
C114.5															2
C114.4	3	2	3	-	-	-	-	2	-	-	-		-	2	2
C114.5	3	2	3	-	-	-	-	2	-	-	-		-	2	2
C114.6	3	2	3	2	-	-	-	2	-	-	-		-	2	2
				C 1	115/EC3	27/ Cir	cuit Ar	alysis I	abora	atory			L		
C115.1	3	2	3	2	2	-	-	-	2	-	2		2	3	2
C115.2	3	2	3	2	2	-	-	-	2	-	2		2	3	2
C115.3	3	2	3	2	2	-	-	-	2	-	2		2	3	2
C115.4	3	2	3	2	2	-	-	-	2	-	2		2	3	2
C115.5	3	2	3	2	2	-	-	-	2	-	2		2	3	2
C115.6	3	2	3	2	2	-	-	-	2	ı	2		2	3	2
			C	201/MA	A3355/ R	andom	Proces	sses and	Line	ar Algeb	ra				
C201.1	3	3	-	-	-	-	-	-	3	_	-		2	2	2
C201.2	3	3	-	-	-	-	-	-	3	-	-		2	2	2
C201.3	3	3	-	-	-	-	-	-	3	-	-		2	2	2
C201.4	3	3	-	-	-	-	-	-	3	-	-		2	2	2
C201.5	3	3	-	-	-	-	-	-	3	-	-		2	2	2
C201.6	3	3	-	-	-	-	-	-	3	-	-		2	2	2
	1	l l		C202/C	CS3353/0	C Progr	ammir	ng and I	Data S	Structure	es	I		<u> </u>	
C202.1	2	3	1	2	2	1	1	-		1 2	2	1	3	3	2
C202.2	1	2	1	2	2	-	-	-		1	1	1	2	3	2
C202.3	2	3	1	2	3	-	-	-		1	1	1	2	3	2
C202.4	2	1	-	1	1	-	-	-		2	1	1	2	3	2
C202.5	1	2	1	2	2	1	1	-		1	2	1	3	3	2

					C203/	EC3354/ S	Signals a	and Sys	tems					
C203.1	3	-	3	-	3	2	-	-	-	-	-	3	3	3
C203.2	3	-	3	-	-	2	-	-	-	-	-	3	2	3
C203.3	3	3	-	-	3	2	-	-	-	-	-	3	3	2
C203.4	3	3	-	-	3	2	-	-	-	-	-	3	2	2
C203.5	3	3	-	3	3	2	-	-	-	-	-	3	3	2
C203.6	3	3	3	3	3	2	-	-	-	-	-	3	2	2
				C20	4/ EC33	53/ Electr	onic De	vices an	d Circu	iits				
C204.1	3	3	3	3	2	1	-	-	-	-	-	1	3	1
C204.2	3	2	2	3	2	2	-	-	-	-	-	1	3	1
C204.3	3	3	3	2	1	2	-	-	-	-	-	1	3	1
C204.4	3	3	2	3	2	2	-	1	-	-	-	1	3	1
C204.5	3	2	3	2	2	1	-	-	-	-	-	1	3	1
C204.6	3	2	3	2	2	1	-	-	-	-	-	1	3	1
					C205	5 /EC3351	/ Contr	ol Syste	ms					
C205.1	3	3	3	2	2	2	-	1	-	1	2	3	2	2
C205.2	3	3	3	3	2	3	-	-	-	-	2	2	2	2
C205.3	3	2	3	3	2	2	-	1	-	-	2	3	2	2
C205.4	3	3	3	2	2	2	-	1	-	-	2	2	2	2
C205.5	2	2	3	3	2	3	-	-	-	-	2	3	2	2
C205.6	3	3	3	3	2	2	-	-	-	-	2	3	2	2
					C206 / E	EC3352/ D	igital S	ystems l	Design					
C206.1	3	2	2	2	-	2	-	-	-	-	3	3	3	2
C206.2	-	-	-	-	-	-	-	-	-	-	2	1	3	3
C206.3	-	3	3	2	-	2	-	-	-	-	2	2	2	2
C206.4	-	-	-	-	-	-	-	-	-	-	3	2	3	3

C206.5	-	3	3	3	-	-	-	-	-	-	2	2	2	2
C206.6	3	3	3	2	-	2	-	-	-	-	2	2	3	3
			C20'	7 /EC	3361/ El	ectronics (devices	and circ	cuits La	borator	y			
C207.1	2	2	3	3	2	1	-	-	-	-	-	1	3	2
C207.2	2	2	3	3	2	1	-	-	-	-	-	1	3	2
C207.3	2		2		1	1	-	-	-	-	-	1	3	2
C207.4	-	-	-	-	3	1	-	-	-	-	-	1	3	2
C207.5	-	-	-	-	2	1	-	-	-	-	-	1	3	2
C207.6	2	2	2	3	2	1	-	-	-	-	-	1	3	2
			C208 /0	CS336	62/ C Pro	grammin	g and D	ata Str	uctures	Labora	tory			
C208.1	2	3	1	2	2	1	1	-	1	2	1	2	3	2
C208.2	1	2	1	2	2	-	-	-	1	1	1	1	3	2
C208.3	2	3	1	2	3	-	-	-	1	1	1	2	3	2
C208.4	2	1	-	1	1	-	-	-	2	1	1	2	3	2
C208.5	1	2	1	2	2	1	1	-	1	2	1	1	3	2
C208.6	2	2	1	2	2	1	1	-	1	1	1	2	3	2
					C209/E	C3452/ El	ectroma	agnetic	Fields					
C209.1	2	1	1	1	-	2	1	-	-	1	-	2	3	3
C209.2	2	2	3	3	2	2	2	-	-	1	1	2	2	3
C209.3	2	2	3	2	2	2	1	-	-	1	1	2	3	2
C209.4	2	2	3	2	2	2	1	-	-	1	1	2	2	2
C209.5	2	2	2	2	2	2	1	-	-	2	2	1	3	2
C209.6	2	2	2	2	2	2	1	-	-	1	1	2	2	2
					C210 /E	C3401/N	etworks	and Se	curity					
C210.1	3	2	2	-	-	-	-	-	2	-	-	2	2	2
C210.2	3	3	-	-	-	-	-	-	-	-	-	2	2	2

C210.3	3	2	-	-	-	-	-	-	-	-	-	-	2	2
C210.4	3	3	2	-	2	2	-	2	2	-	-	3	2	2
C210.5	3	3	2	-	2	2	-	2	2	-	-	3	2	2
C210.6	3	2	2	-	-	-	-	-	-	-	-	2	2	2
				(C211/EC	3451/Line	ar Inte	grated (Circuits					
C211.1	2	-	-		-	-	-	-	-	-	1		2	2
C211.2	2	3	3	2	-	-	-	-	-	-	-	-	2	2
C211.3	1	-	-	2	-		-	-	-	-	-	-	2	2
C211.4	1	-	-	2	-	-	-	-	-	-	-	-	2	2
C211.5	1	2	3	3	-	-	-	-	-	-	-	3	2	2
C211.6	1	2	3	2	-	-	-	-	-	-	1	3	2	2
'				I.	C212/E(C3492/Dig	ital Sig	nal Proc	cessing			I		
C212.1	3	3	3	3	2	2	-	-	-	-	1	1	3	2
C212.2	3	3	3	3	2	2	-	-	-	-	1	1	2	2
C212.3	3	3	2	2	2	2	-	-	-	-	1	1	2	2
C212.4	3	3	2	2	3	1	-	-	-	-	1	1	2	3
C212.5	3	2	2	2	3	2	-	-	-	-	1	1	2	1
C212.6	3	2	2	2	3	2	-	-	-	-	1	1	2	1
				•	C213/ E	C3491/Co	mmunic	ation S	ystems					
C213.1	3	3	2	2	2	-	-	-	-	-	-	-	2	2
C213.2	3	3	3	3	3	-	ı	ı	-	ı	ı	-	2	2
C213.3	3	2	3	2	3	-	ı	ı	-	ı	ı	ı	2	2
C213.4	3	3	2	2	2	-	-	-	-	-	-	-	2	2
C213.5	3	3	2	2	3	-	-	-	-	-	-	-	2	2
C213.6	3	3	2	2	3	-	-	-	-	-	-	-	2	2

		(GE3451/	ENVI	RONME	ENTAL SO	CIENCI	ES AND	SUST	AINAB	ILITY			
C214.1	2	1	-	-	-	2	3	-	-	-	-	2	-	-
C214.2	3	2	-	-	-	3	3	-	-	-	-	2	-	-
C214.3	3	-	1	-	-	2	2	-	-	-	-	2	-	-
C214.4	3	2	1	1	-	2	2	-	-	-	-	2	-	-
C214.5	3	2	1	-	-	2	2	-	-	-	-	1	-	-
C214.6	3	2	1	-	-	2	2	-	-	-	-	1	-	-
			(C215/	EC3461	/ Commu	nication	System	ns Labo	ratory				
C215.1	2	-	-	-	-	2	2	-	2	3	-	2	2	2
C215.2	2	-	-	-	-	2	2	-	2	3	-	2	2	2
C215.3	2	-	-	-	-	2	2	-	2	3	-	2	2	2
C215.4	3	-	-	-	-	3	2	-	2	3	-	3	2	2
C215.5	3	-	-	-	-	3	2	-	2	3	-	3	2	2
C215.6	2	-	1	-	-	2	3	-	2	3	-	2	2	2
			(C 216 /	EC3462/	Linear In	tegrated	d Circui	its Labo	ratory				
C216.1	2	-	-	-	-	-	-	-	-	-	1	-	2	2
C216.2	2	3	3	2	-	-	-	_	-	-	-	-	2	2
C216.3	1	-	-	2	-		-	-	-	-	-	-	2	2
C216.4	1	-	-	2	-	-	-	-	-	-	-	-	2	2
C216.5	2	2	3	3	-	-	-	-	-	-	1	2	2	2
C216.6	2	2	3	2	-	-	-	-	-	-	1	2	2	2
					C301 /E(C3501/Wi	reless C	ommun	ication			_	_	
C301.1	2	-	-	-	-	-	-	-	-	-	1	-	1	2
C301.2	2	3	3	2	-	-	-	-	-	-	-	-	1	2
C301.3	2	3	3	2	-	-	-	-	-	-	-	-	1	2

	1											I	1	2
C301.4	1	-	-	2	-		-	-	-	-	-	-	1	2
C301.5	1	-	-	2	-	-	-	-	-	-	-	-	1	2
C301.6	1	2	3	3	-	-	-	-	-	-	-	3	1	2
					C302/ I	EC3552/V	LSI and	Chip I	Design					
C302.1	3	2	1	2	-	-	-	-	-	2	2	3	3	1
C302.2	3	3	1	2	-	-	-	-	-	2	2	3	3	1
C302.3	3	3	1	2	-	-	-	-	1	2	2	3	3	1
C302.4	3	2	2	2	-	-	-	-	ı	2	2	2	3	1
C302.5	3	2	2	2	-	-	-	-	-	2	2	2	3	1
C302.6	3	2	2	2	-	-	-	-	-	2	2	2	3	1
			ı	C303/	EC3551	Transmis	sion Li	nes and	RF Sys	tems				
C303.1	3	3	3	3	2	2	_	-	_	2	_	2	2	2
C303.2	3	2	2	3	2	2	-	_	_	2	-	2	2	2
C303.3	3	3	3	2	2	2	_	_	_	2	_	2	2	2
C303.4	3	3	2	3	2	2	-	_	-	2	_	2	2	2
C303.5	3	2	3	2	2	2	_	_	-	2	_	2	2	2
C303.6	3	2	2	2	2	2	_	_	_	2	_	2	2	2
						Optical C	ommun	ication	and Ne			<u> </u>	<u> </u>	
C304.1	3	3	2	3	3	1	-	-	-	-	2	2	2	2
C304.2	3	3	2	1	3	2	-	-	-	-	2	2	2	2
C304.3	3	3	3	3	2	1	-	-	-	-	2	2	2	2
C304.4	3	3	2	2	2	1	-	-	-	-	2	2	2	2
C304.5	3	3	3	3	2	1	-	-	-	-	2	2	2	2
C304.6	3	3	3	3	2	1	-	-	-	-	2	2	2	2
					C305	/ CEC366	/Image	Process	sing			<u> </u>		
C305.1	3	3	3	2	2	2	-	-	-	-	-	3	3	2
C305.2	3	3	3	2	2	2	-	_	-	_	_	2	3	2

	-							1	1	1	ı	1 -		
C305.3	3	3	2	2	2	2	-	-	-	-	-	2	3	2
C305.4	3	3	3	2	2	2	-	-	-	-	-	2	3	2
C305.5	3	3	3	3	2	2	-	-	-	-	-	2	2	2
C305.6	3	3	3	2	2	2	-	-	-	-	-	2	2	2
				(C306 /CI	EC352/Sat	ellite C	ommun	ication			•		
C306.1	2	-	2	-	-	3	-	3	-	2	-	2	2	3
C306.2	2	-	2	-	-	3	-	3	-	2	-	2	2	3
C306.3	2	-	2	-	-	3	-	3	-	2	-	2	2	3
C306.4	2	-	2	-	-	3	-	3	-	2	-	2	2	3
C306.5	2	-	2	-	-	3	-	3	-	2	-	2	2	3
C306.6	2	-	2	-	-	3	-	3	-	2	-	2	2	3
			C30)7/ M	X3084/D	isaster Ri	sk redu	ction ar	nd mana	agemen	t	•		
C307.1	3	3	2	3	-	-	2	2	-	-	2	2	1	1
C307.2	3	3	3	3	-	-	2	1	-	-	2	2	1	1
C307.3	3	3	3	3	-	-	2	2	-	-	-	-	1	1
C307.4	3	3	2	3	-	-	2	1	-	-	2	-	1	1
C307.5	3	3	2	3	-	-	2	2	-	-	2	-	1	1
C307.6	3	3	3	3	-	-	2	2	-	-	2	-	1	1
					C308	/ EC3561	/VLSI I	Laborat	ory					
C308.1	3	3	2	2	-	-	-	-	-	-	2	3	3	1
C308.2	3	3	2	2	-	-	-	-	-	-	2	3	3	1
C308.3	3	3	2	2	-	-	-	-	-	-	2	3	3	1
C308.4	3	3	2	2	-	-	-	-	-	-	2	2	3	1
C308.5	3	3	2	2	-	-	-	-	-	-	2	2	3	1
C308.6	3	3	2	2	-	-	-	-	-	-	2	2	3	1

S.No						Cou	rse-PO	/PSO I	MAPPI	NG				
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO1 0	PO1 1	PO1 2	PSO1	PSO2
C101	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C102	3	3	2.4	2.4	2	-	-	-	-	-	-	2	-	2
C103	3	3	2	2	2	2.67	2	-	-	-	-	2	3	3
C104	3	2.83	2	2	2	2	2	-	2	-	-	2	-	2
C105	3	2	2	2	2	2	-	2	-	-	-	-	-	3
C106	3	2.4	3	2	-	-	-	-	-	-	-	-	-	-
C107	2.5	2.33	-	2.33	-	-	2	2	2.33	-	-	2	2	-
C108	3	3	-	-	2	3	2	2	2	3	-	2	-	2
C109	3	2.8	2	2	2	2	-	-	-	-	-	2.2	-	2
C110	3	2.17	-	2	2	-	2	-	-	-	-	2	2	1
C111	2.67	2.67	2	2	2	2	2	-	2	-	2	2	2	1
C112	3	3	3	2	2	-	-	-	-	2	2	2	3	3
C113	3	2	2	-	2	-	-	-	-	-	ı	2	-	2
C114	3	2.4	3	2	-	-	-	2	-	-	-	-	2	2
C115	3	2	3	2	2	-	-	-	2	-	2	2	3	2
C201	3	3	-	-	-	-	-	-	3	-	-	2	2	2
C202	1.67	2.17	1	1.83	2	1	1	-	1.17	1.33	1	2.33	3	2
C203	3	3	3	3	3	2	-	-	-	-	-	3	2.5	2.33
C204	3	2.5	2.67	2.5	1.83	1.5	-	-	-	-	-	1	3	1

C205	2.83	2.67	3	2.67	2	2.33	-	-	-	-	2	2.67	2	2
C206	3	2.75	2.75	2.25	-	2	-	-	-	-	2.33	2	2.67	2.5
C207	2	2	2.5	3	2	1	-	-	-	-	-	1	3	2
C208	1.67	2.17	1	1.83	2	1	1	-	1.17	1.33	1	1.67	3	2
C209	2	1.83	2.33	2	2	2	1.17	-	-	1.17	1.2	1.83	2.5	2.33
C210	3	2.5	2	-	2	2	-	2	2	-	-	2.4	2	2
C211	1.33	2.33	3	2.2	-	-	-	-	-	-	1	3	2	2
C212	3	2.67	2.33	2.33	2.5	1.83	-	-	-	-	1	1	2.17	1.83
C213	3	2.83	2.33	2.17	2.67	-	-	-	-	-	-	-	2	2
C214	2.83	1.8	1	1	-	2.17	2.33	-	-	-	-	1.667	-	-
C215	2.33	-	-	-	-	2.33	2.17	-	2	3	-	2.33	2	2
C216	1.67	2.33	3	2.2	-	-	-	-	-	-	1	2	2	2
C301	1.5	2.67	3	2.2	-	-	-	-	-	-	1	3	1	2
C302	3	2.33	1.5	2	-	-	-	-	-	2	2	2.5	3	1
C303	3	2.5	2.5	2.5	2	2	-	-	-	2	-	2	2	2
C304	3	3	2.5	2.5	2.33	1.17	-	-	-	-	2	2	2	2
C305	3	3	2.83	2.17	2	2	-	-	-	-	-	2.17	2.67	2
C306	2	-	2	-	-	3	-	3	-	2	-	2	2	3
C307	3	3	2.5	3	-	-	2	1.67	-	-	2	2	1	1
C308	3	3	2	2	-	-	-	-	-	-	2	2.5	3	1